

MBRS2535CT THRU MBR2560CT

SCHOTTKY BARRIER RECTIFIER



康比電子
HORNBY ELECTRONIC

REVERSE VOLTAGE: 35 to 60 VOLTS

FORWARD CURRENT: 25.0 AMPERE

FEATURES

- For surface mounted application
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- For use in low voltage,high frequency inverters,free whelling,and polarity protection applications
- High temperature soldering guaranteed:
250°C/10 seconds, 0.25" (6.35mm) from case

MECHANICAL DATA

Case: Molded plastic, D²PAK

Epoxy: UL 94V-O rate flame retardant

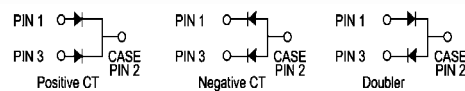
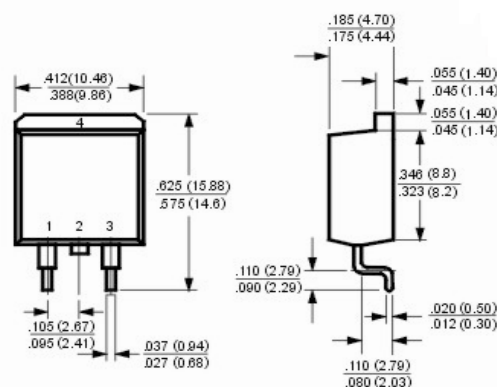
Terminals: Leads solderable per MIL-STD-202
method 208 guaranteed

Polarity: As marked

Mounting position: Any

Weight: 0.06ounce, 1.70gram

D²PAK



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	MBRS2535CT	MBRS2545CT	MBRS2550CT	MBRS2560CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	Volts
Maximum RMS Voltage	V_{RMS}	24	31	35	42	Volts
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	Volts
Maximum Average Forward Rectified Current at $T_C = 130^\circ C$	$I_{(AV)}$	30.0				Amp
Peak repetitive forward current at $T_C = 130^\circ C$ (rated VR, sq. wave, 20 KHz)	I_{FRM}	30.0				Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	150				Amp
Peak repetitive reverse current at $t_p = 2.0\mu s$, 1KHz	I_{RRM}	1.0		0.5		Amp
Maximum Forward Voltage (Note 1)	V_F					Volts
at $I_F = 15A$, $T_C = 25^\circ C$		-		0.75		
at $I_F = 15A$, $T_C = 125^\circ C$		-		0.65		
at $I_F = 30A$, $T_C = 25^\circ C$		0.82		-		
at $I_F = 30A$, $T_C = 125^\circ C$		0.73		-		
Maximum Reverse Current at $T_C = 25^\circ C$	I_R	0.2		1.0		mAmp
at Rated DC Blocking Voltage $T_C = 125^\circ C$		40		50		
Voltage rate of change (rated V_R)	dv/dt	10,000				V/ μs
Typical Thermal Resistance	$R_{\theta JC}$	1.5				$^\circ C/W$
Operating Temperature Range	T_J	-55 to +150				$^\circ C$
Storage Temperature Range	T_{stg}	-55 to +175				$^\circ C$

NOTES:

1- Pulse test: 300 μs pulse width, 1% duty cycle

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RATINGS AND CHARACTERISTIC CURVES

